





## IF4500 N-Channel JFET

### Features

- InterFET <u>N0450L Geometry</u>
- Low noise: 0.85 nV/VHz typical
- High gain: 65mS typical
- Low gate leakage: 1.5pA typical @10V
- Low VGS(OFF): -1.0 typical
- Typical Ibss: 30mA
- Typical BVgss: -35V
- High radiation tolerance
- RoHS, REACH, CMR compliant
- Custom test and binning options available
- SMT, TH, and bare die package options
- Edge case SPICE modeling: InterFET SPICE

### **Industry Standard Crosses**

• J110, J110A, 2SK363, MMBFJ110

### **InterFET Similar Parts**

• 2N6550, IF4510, IF4520, IFN363, SMPJ110

### **InterFET Dual Parts**

IFN860, SMP860

### **Applications**

- · General: Amplifiers; Switches; Voltage regulators; Oscillators; Signal mixers; Noise generators
- Military/Aero: Radar; Communications; Satellites; Missiles guidance; Hydrophone Pre-Amps
- Medical: Medical imaging systems; Medical monitors and recorders; Ultrasound equipment
- Audio: Tone control circuits; Headphone amplifiers; Audio filters; Electret Microphone

### Description

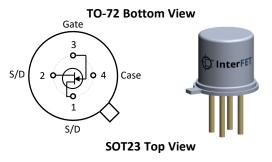
The -20V InterFET IF4500 JFET is targeted for low noise high gain amplifier designs. The IF4500 is ideal for low-voltage supply application with a cutoff voltage of less than -1.5V. The InterFET proprietary JFET recipes result in highest radiation tolerance and lowest leakage JFETs on the market. Custom binning options available.

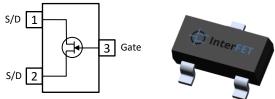
Part Number	Description	Case	Packaging
IF4500T72	Through-Hole	TO-72	Bulk
IF4500ST3	Surface Mount	SOT23	Bulk
	7" Tape and Reel: Max 3,000 Pieces		Minimum 1,000 Pieces
IF4500ST3TR	13" Tape and Reel: Max 9,000 Pieces	SOT23	Tape and Reel
IF4500COT	Chip Orientated Tray (COT Waffle Pack)	СОТ	400/Waffle Pack
IF4500CFT	Chip Face-up Tray (CFT Waffle Pack)	CFT	400/Waffle Pack

#### Ordering Information Custom Part and Binning Options Available



NOTICE: Please refer to the end of this document for information on product materials, compliance, safety, and legal statements.





NOTE: S/D pins are interchangeable Source Drain connections







### **Electrical Characteristics**

### Maximum Ratings (@ TA = 25°C, Unless otherwise specified)

	Parameters	TO-18	SOT-23	Unit
VRGS	Reverse Gate Source and Gate Drain Voltage	-20	-20	V
IFG	Continuous Forward Gate Current	50	50	mA
PD	Continuous Device Power Dissipation <sup>1</sup>	500	350	mW
Р	Power Derating <sup>1</sup>	3.3	2.8	mW/°C
Tj	Operating Junction Temperature	-65 to 175	-55 to 150	°C
Tstg	Storage Temperature	-65 to 175	-55 to 150	°C

<sup>1</sup> Thermal power dissipation and derating values obtained with gate pin (substrate) thermally connected to pad and/or internal layer.

### Static Characteristics (@ TA = 25°C, Unless otherwise specified)

	Parameters	Conditions	Min	Тур	Max	Unit
V(BR)GSS	Gate to Source Breakdown Voltage	$V_{DS} = 0V$ , $I_G = -1\mu A$	-20			V
I <sub>GSS</sub>	Gate to Source Reverse Current	$V_{GS} = -20V, V_{DS} = 0V$			-0.1	nA
Vgs(off)	Gate to Source Cutoff Voltage	V <sub>DS</sub> = 15V, I <sub>D</sub> = 0.5nA	-0.35		-1.5	V
I <sub>DSS</sub>	Drain to Source Saturation Current	$V_{GS} = OV, V_{DS} = 15V$ (Pulsed)	5	30		mA

### Dynamic Characteristics (@ TA = 25°C, Unless otherwise specified)

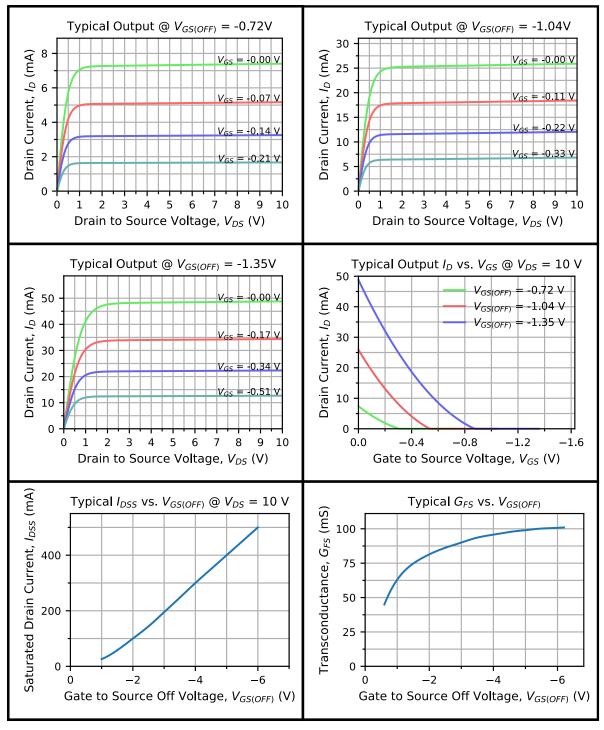
	Parameters	Conditions	Min	Тур	Max	Unit
Gfs	Forward Transconductance	V <sub>DS</sub> = 15V, I <sub>D</sub> = 5mA, f = 1kHz	15	70		mS
C <sub>iss</sub>	Input Capacitance	$V_{DS}$ = 15V, $V_{GS}$ = 0V, f = 1MHz			35	pF
Crss	Reverse Transfer Capacitance	V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V, f = 1MHz			15	pF
en	Equivalent Circuit Input Noise Voltage	V <sub>DS</sub> = 4V, I <sub>D</sub> = 5mA, f = 1kHz		0.85		nV/√Hz







### **Typical IF4500 Characteristics**







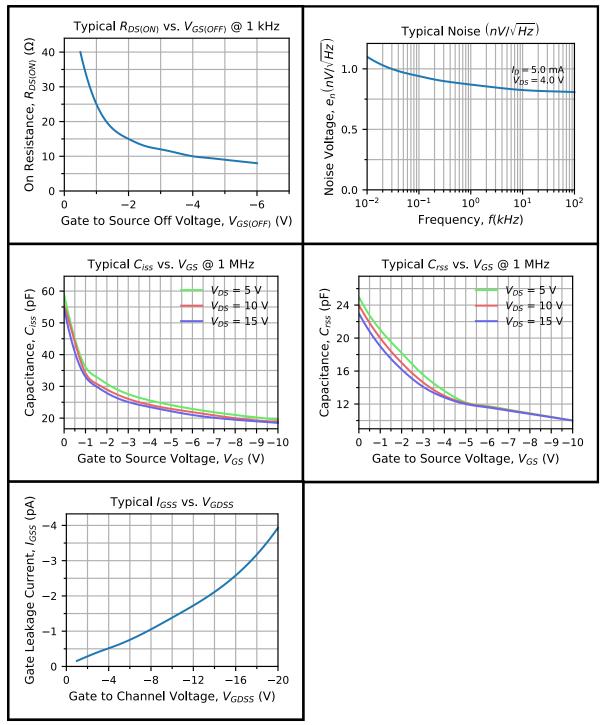
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Technical

Support

# IF4500

### Typical IF4500 Characteristics (Continued)





Technical

Support

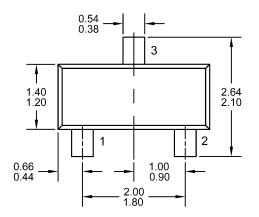
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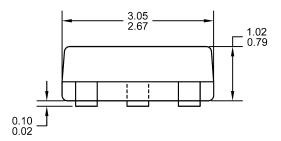
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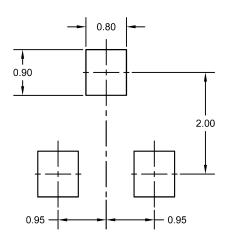
### SOT23 (TO-236AB) Mechanical and Layout Data

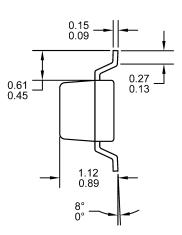
### **Package Outline Data**





### **Suggested Pad Layout**





- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.12 grams
- 3. Molded plastic case UL 94V-0 rated
- For Tape and Reel specifications refer to InterFET CTC-021 Tape and Reel Specification, Document number: IF39002
- 5. Bulk product is shipped in standard ESD shipping material
- 6. Refer to JEDEC standards for additional information.

- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided for reference only. A more robust pattern may be desired for wave soldering.

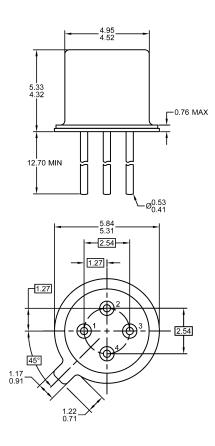




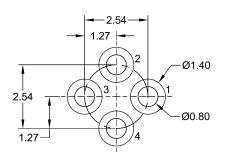
# IF4500

### **TO-72 Mechanical and Layout Data**

### **Package Outline Data**



### Suggested Through-Hole Layout



- 1. All linear dimensions are in millimeters.
- 2. Four leaded device. Not all leads are shown in drawing views.
- 3. Package weight approximately 0.31 grams
- 4. Bulk product is shipped in standard ESD shipping material
- 5. Refer to JEDEC standards for additional information.

- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.







### **Compliance and Legal**

#### Environment

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#### **Package materials**

Parameters	SOT23	SOIC8	TO-92	Metal Case
Alloy	CDA194	C194 1/2H	C194 1/2H	Kovar
Cu	Balance	97% min	97% min	
Fe	2.1 - 2.6%	2.1 - 2.6%	2.1 - 2.6%	53%
Zn	0.05 – 0.2%	0.05 – 0.2%	0.05 - 0.15%	
Р	0.015 - 0.15%	0.015 – 0.15%	0.015 - 0.15%	
Pb	0.03% max	0.03% max	0.03% max	
Ni				29%
Со				17%
Mn				0.3%
Si				0.2%
С				<0.01%
Au				Plating

#### **Package tests**

Parameters	Parameters SOT23 S		TO-92	Metal Case
MSL	Level 1	Level 1	N/A	N/A
ESD	Class M4 Machine Model			
	Class 3B HBM	Class 3B HBM	Class 3B HBM	Class 3B HBM

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